

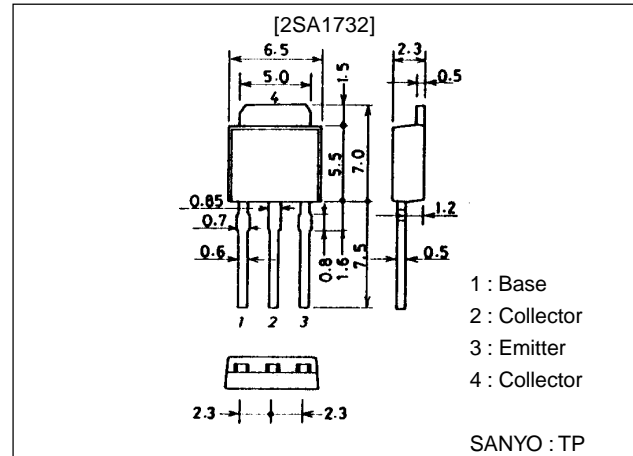
**2SA1732****High-Speed Switching Applications****Features**

- Adoption of FBET processes.
- Large current capacity.
- Low collector-to-emitter saturation voltage.
- Fast switching speed.

Package Dimensions

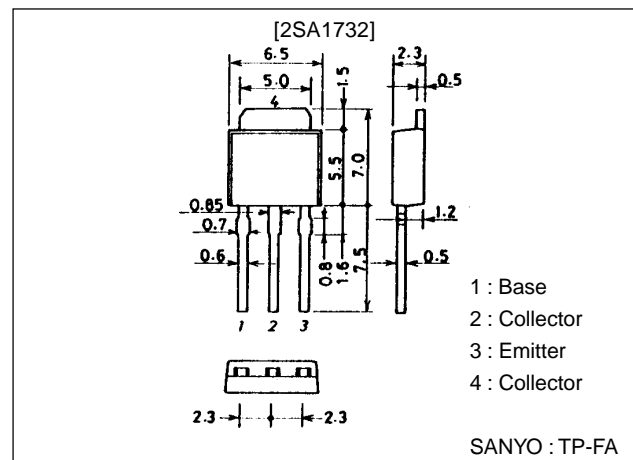
unit:mm

2045B



unit:mm

2044B



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SANYO Electric Co.,Ltd. Semiconductor Business Headquarters

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Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		-50	V
Collector-to-Emitter Voltage	V_{CEO}		-40	V
Emitter-to-Base Voltage	V_{EBO}		-5	V
Collector Current	I_C		-8	A
Collector Current (Pulse)	I_{CP}		-12	A
Collector Dissipation	P_C		1	W
		$T_C=25^\circ\text{C}$	15	W
Junction Temperature	T_J		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

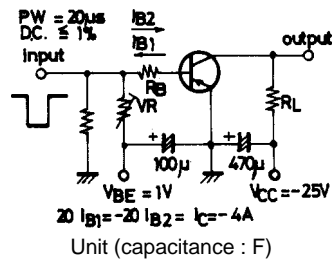
Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=-40\text{V}, I_E=0$			-1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=-3\text{V}, I_C=0$			-1	μA
DC Current Gain	h_{FE1}	$V_{CE}=-2\text{V}, I_C=-500\text{mA}$	70*		280*	
	h_{FE2}	$V_{CE}=-2\text{V}, I_C=-8\text{A}$	25			
Gain-Bandwidth Product	f_T	$V_{CE}=-2\text{V}, I_C=-500\text{mA}$		250		MHz
Output Capacitance	C_{ob}	$V_{CB}=-10\text{V}, f=1\text{MHz}$		100		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-4\text{A}, I_B=-200\text{mA}$		-0.3	-0.8	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=-4\text{A}, I_B=-200\text{mA}$		-0.95	-1.3	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=-100\mu\text{A}, I_E=0$	-50			V
Collector-to-Emitter Saturation Voltage	$V_{(BR)CEO}$	$I_C=-1\text{mA}, R_{BE}=\infty$	-40			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=-100\mu\text{A}, I_C=0$	-5			V
Turn-ON Time	t_{on}	See specified Test Circuit		50	100	ns
Storage Time	t_{stg}	See specified Test Circuit		120	220	ns
Turn-OFF Time	t_{off}	See specified Test Circuit		150	300	ns

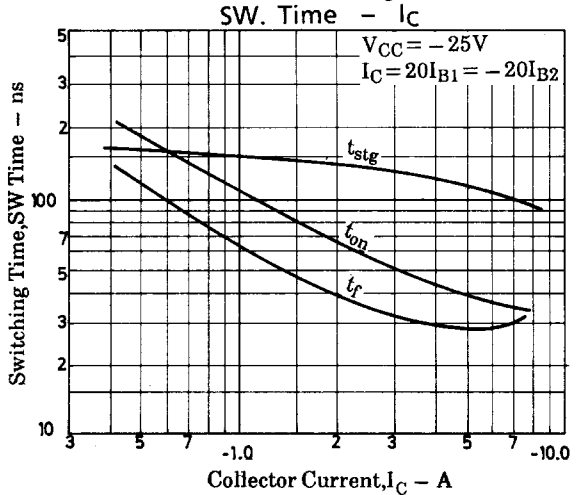
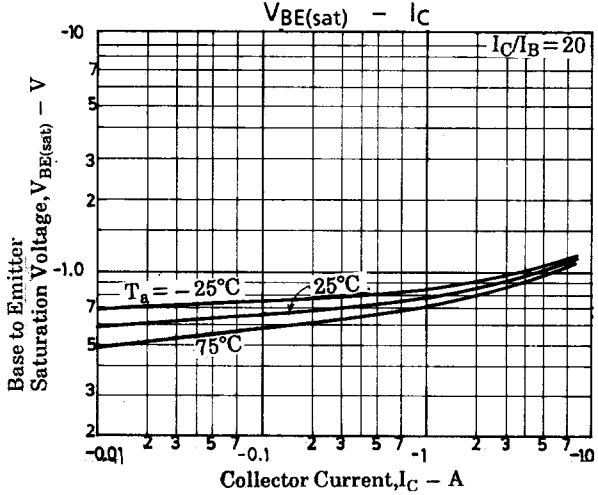
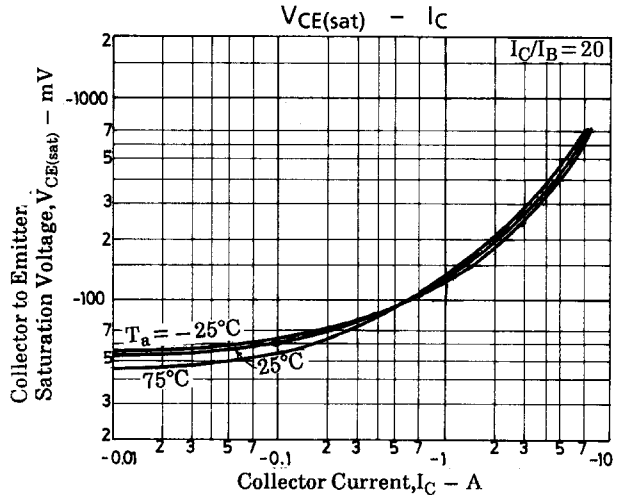
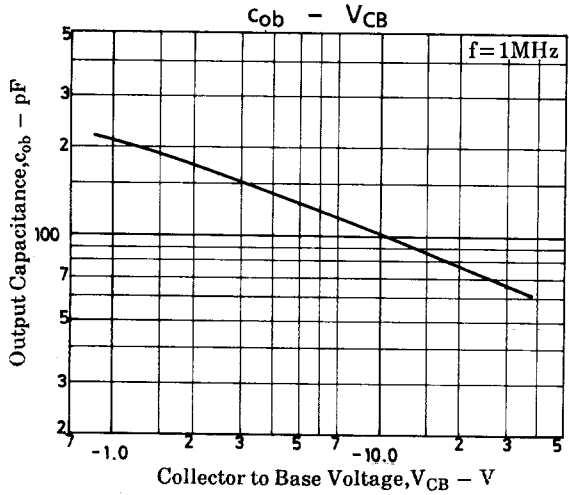
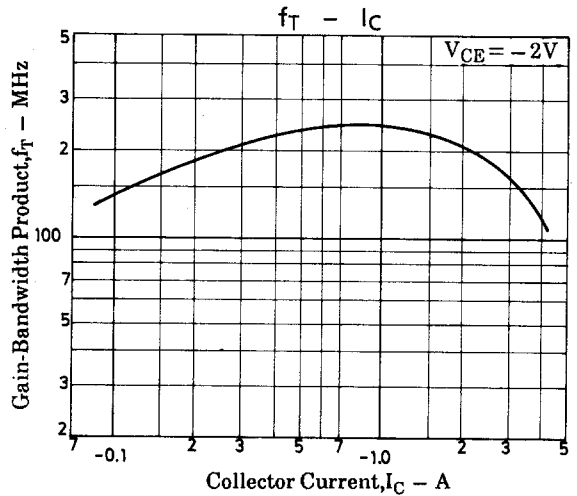
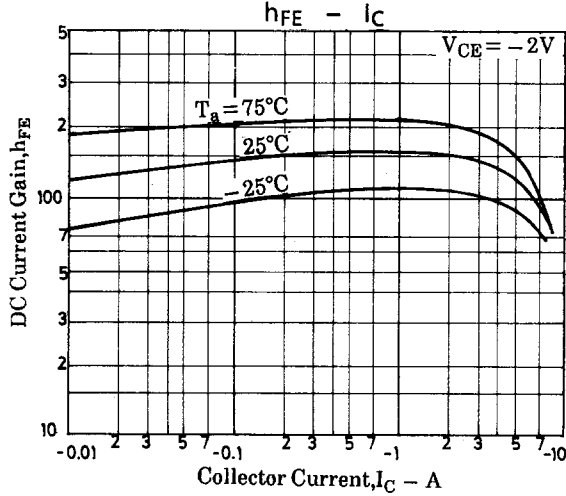
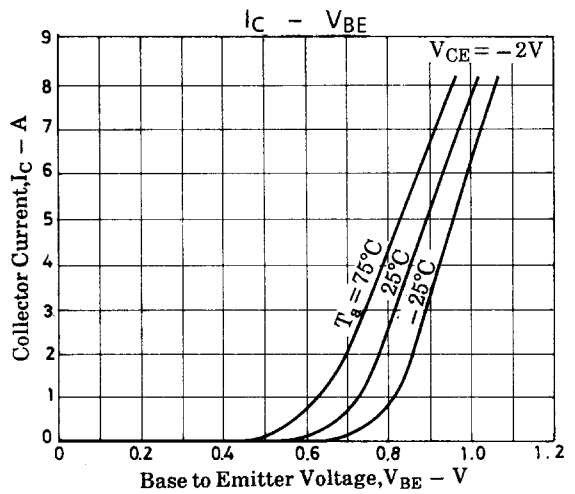
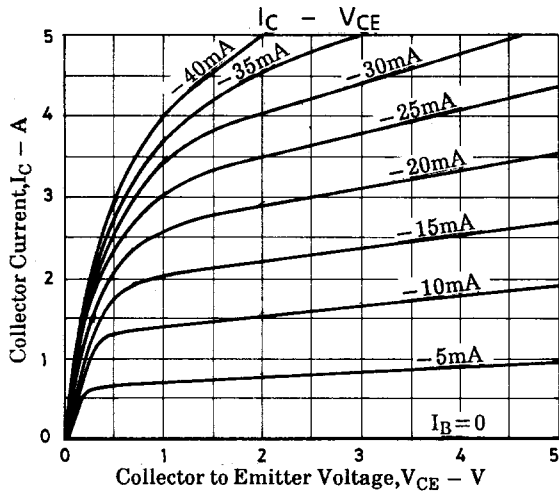
* : The 2SA1732 is classified by 500mA h_{FE} as follows :

70	Q	140	100	R	200	140	S	280
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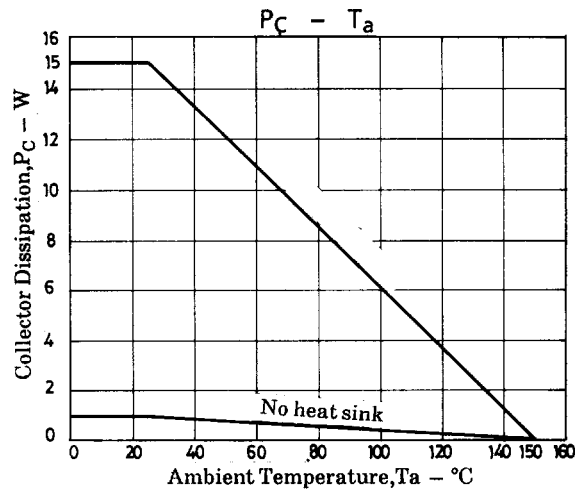
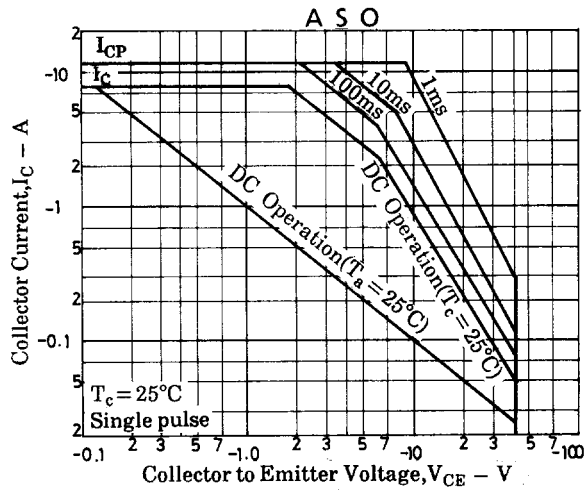
Switching Time Test Circuit



2SA1732



2SA1732



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